



# DATA SHEET

SEMICONDUCTOR

MMBT4403

## General Purpose Transistors

### PNP Silicon

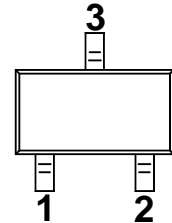


- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish

SOT-23 (TO-236AB)

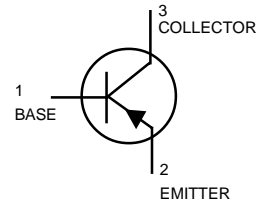
### ORDERING INFORMATION

Device	Package	Shipping
MMBT4403	SOT-23	3000/Tape & Reel



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CE0}$	-40	Vdc
Collector-Base Voltage	$V_{CBO}$	-40	Vdc
Emitter-Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current — Continuous	$I_C$	-600	mAdc



### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (1) $T_A = 25^\circ\text{C}$	$P_D$	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (2) $T_A = 25^\circ\text{C}$	$P_D$	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	°C

### DEVICE MARKING

MMBT4403 = 2T
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### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage (3) ( $I_C = -1.0\text{ mAdc}, I_B = 0$ )	$V_{(BR)CEO}$	-40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = -0.1\text{ mAdc}, I_E = 0$ )	$V_{(BR)CBO}$	-40	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -0.1\text{ mAdc}, I_C = 0$ )	$V_{(BR)EBO}$	-5.0	—	Vdc
Base Cutoff Current ( $V_{CE} = -35\text{ Vdc}, V_{EB} = -0.4\text{ Vdc}$ )	$I_{BEV}$	—	-0.1	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = -35\text{ Vdc}, V_{EB} = -0.4\text{ Vdc}$ )	$I_{CEX}$	—	-0.1	$\mu\text{Adc}$

- FR-5 = 1.0 x 0.75 x 0.062 in.
- Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.
- Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

# ELECTRICAL CHARACTERISTICS

## MMBT4403

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = -0.1 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )	$h_{FE}$	30	—	—
( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		60	—	
( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		100	—	
( $I_C = -150 \text{ mAdc}$ , $V_{CE} = -2.0 \text{ Vdc}$ )(3)		100	300	
( $I_C = -500 \text{ mAdc}$ , $V_{CE} = -2.0 \text{ Vdc}$ )(3)		20	—	
Collector–Emitter Saturation Voltage(3) ( $I_C = -150 \text{ mAdc}$ , $I_B = -15 \text{ mAdc}$ )	$V_{CE(sat)}$	—	-0.4	Vdc
( $I_C = -500 \text{ mAdc}$ , $I_B = -50 \text{ mAdc}$ )		—	-0.75	
Base–Emitter Saturation Voltage (3) ( $I_C = -150 \text{ mAdc}$ , $I_B = -15 \text{ mAdc}$ )	$V_{BE(sat)}$	-0.75	-0.95	Vdc
( $I_C = -500 \text{ mAdc}$ , $I_B = -50 \text{ mAdc}$ )		—	-1.3	

### SMALL-SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ( $I_C = -20 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	200	—	MHz
Collector–Base Capacitance ( $V_{CB} = -10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{cb}$	—	8.5	pF
Emitter–Base Capacitance ( $V_{BE} = -0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{eb}$	—	30	pF
Input Impedance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{ie}$	1.5	15	$k\Omega$
Voltage Feedback Ratio ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	0.1	8.0	$\times 10^{-4}$
Small–Signal Current Gain ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	60	500	—
Output Admittance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{oe}$	1.0	100	$\mu\text{mhos}$

### SWITCHING CHARACTERISTICS

Delay Time	( $V_{CC} = -30 \text{ Vdc}$ , $V_{EB} = -2.0 \text{ Vdc}$ ,	$t_d$	—	15	ns
Rise Time	$I_C = -150 \text{ mAdc}$ , $I_{B1} = -15 \text{ mAdc}$ )	$t_d$	—	20	
Storage Time	( $V_{CC} = -30 \text{ Vdc}$ , $I_C = -150 \text{ mAdc}$ ,	$t_s$	—	225	ns
Fall Time	$I_{B1} = I_{B2} = -15 \text{ mAdc}$ )	$t_f$	—	30	

3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

### SWITCHING TIME EQUIVALENT TEST CIRCUITS

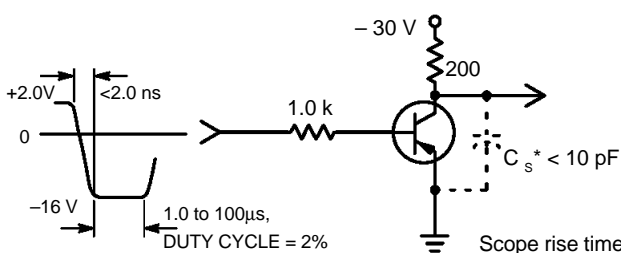


Figure 1. Turn–On Time

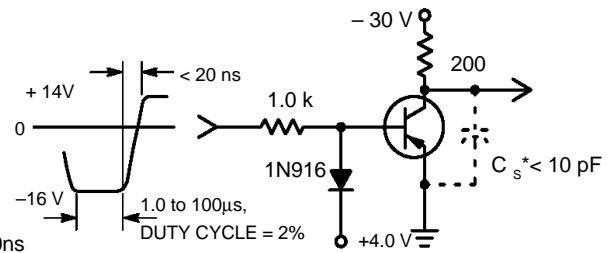


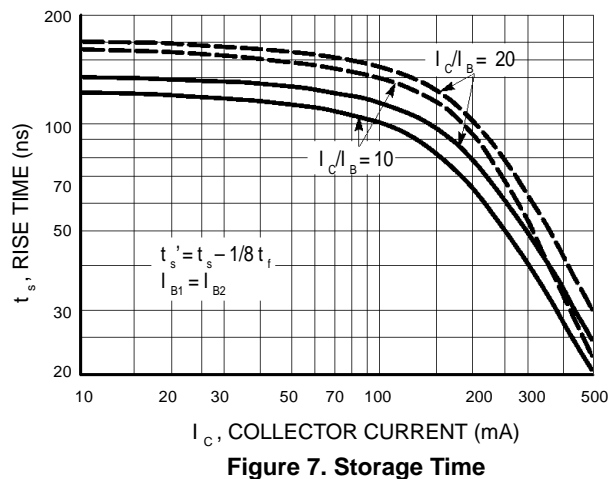
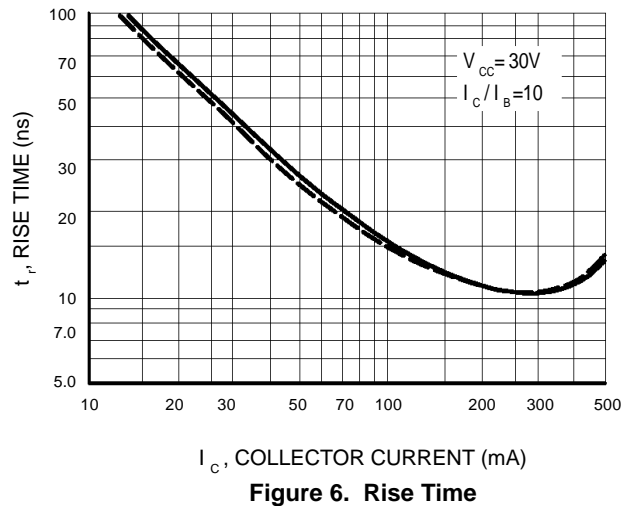
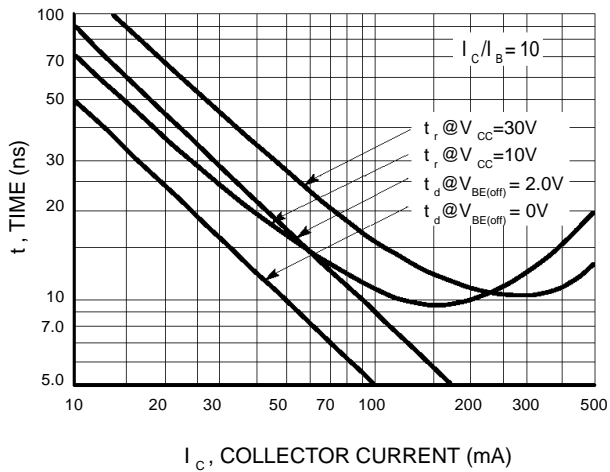
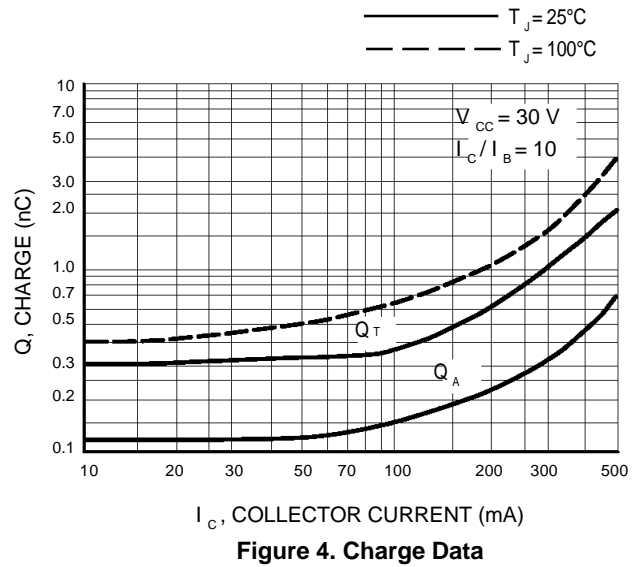
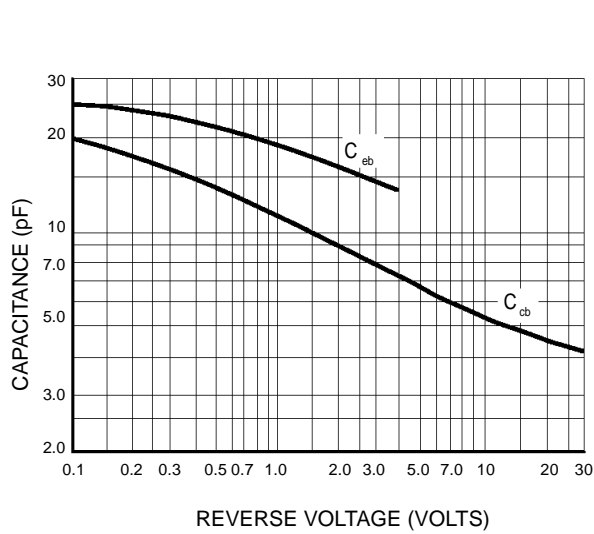
Figure 2. Turn–Off Time

\*Total shunt capacitance of test jig connectors, and oscilloscope

# DEVICE CHARACTERISTICS

## MMBT4403

### TYPICAL TRANSIENT CHARACTERISTICS



# DEVICE CHARACTERISTICS

## MMBT4403

### SMALL-SIGNAL CHARACTERISTICS

#### NOISE FIGURE

$V_{CE} = -10$  Vdc,  $T_A = 25^\circ\text{C}$  Bandwidth = 1.0 Hz

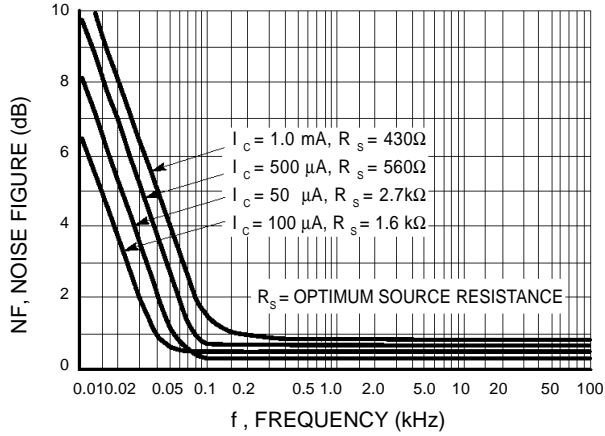


Figure 8. Frequency Effects

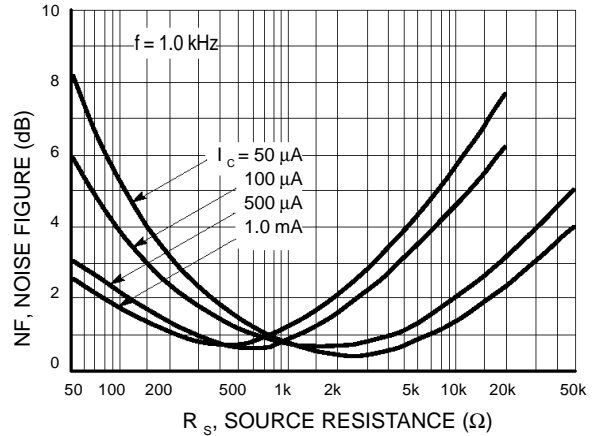


Figure 9. Source Resistance Effects

### h PARAMETERS

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

This group of graphs illustrates the relationship between  $h_{fe}$  and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were selected from the MMBT4403LT1 lines, and the same units were used to develop the correspondingly numbered curves on each graph.

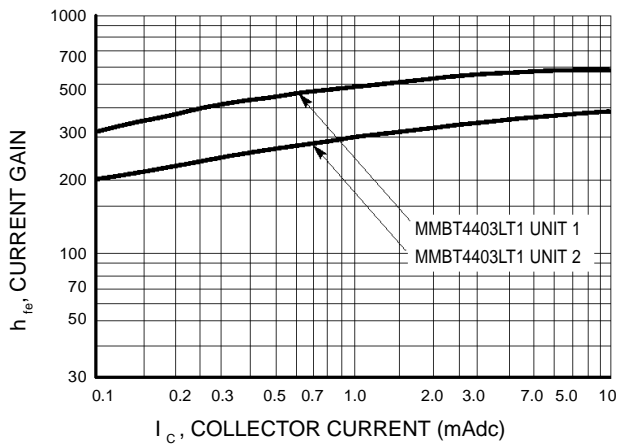


Figure 10. Current Gain

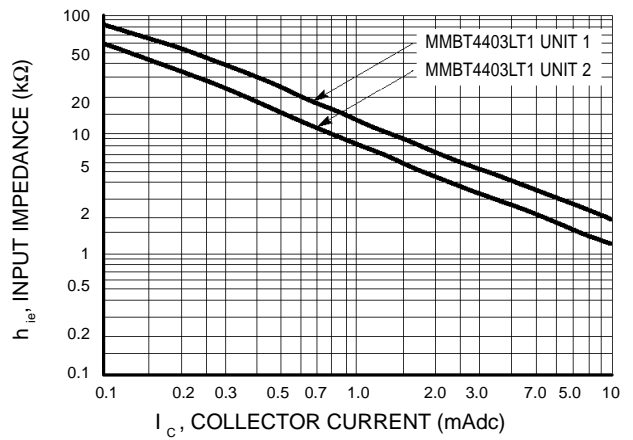


Figure 11. Input Impedance

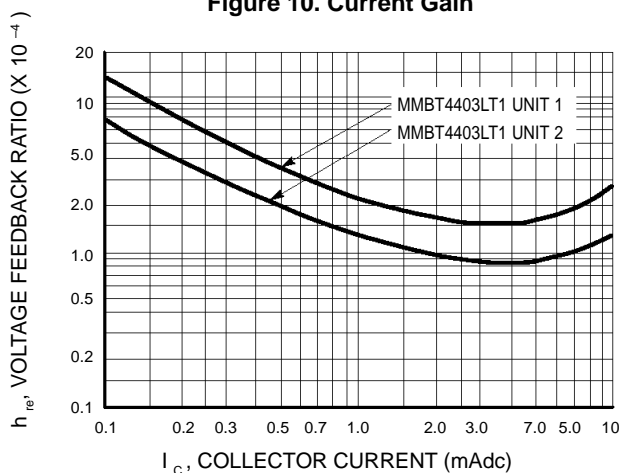


Figure 12. Voltage Feedback Ratio

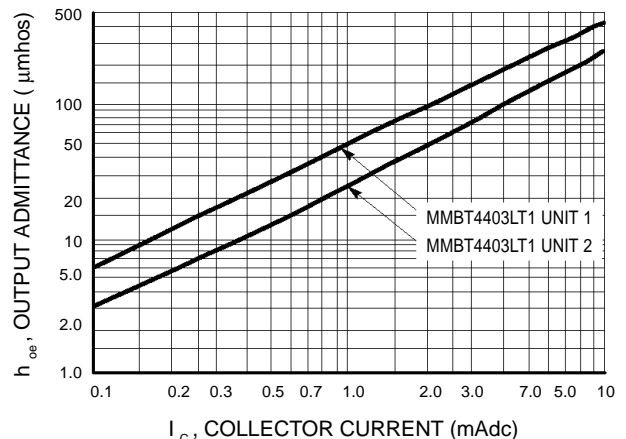


Figure 13. Output Admittance

# DEVICE CHARACTERISTICS

## MMBT4403

### STATIC CHARACTERISTICS

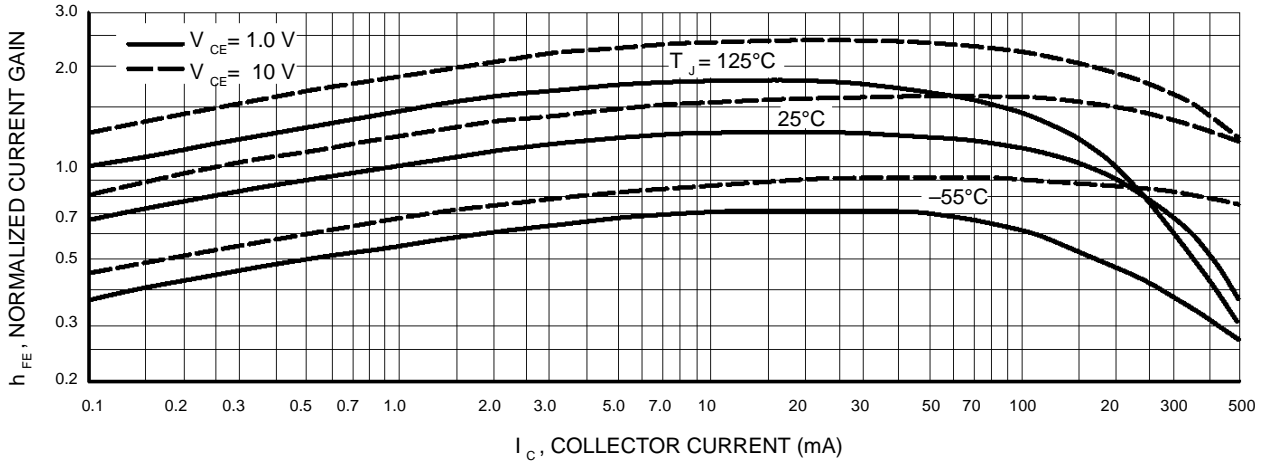


Figure 14. DC Current Gain

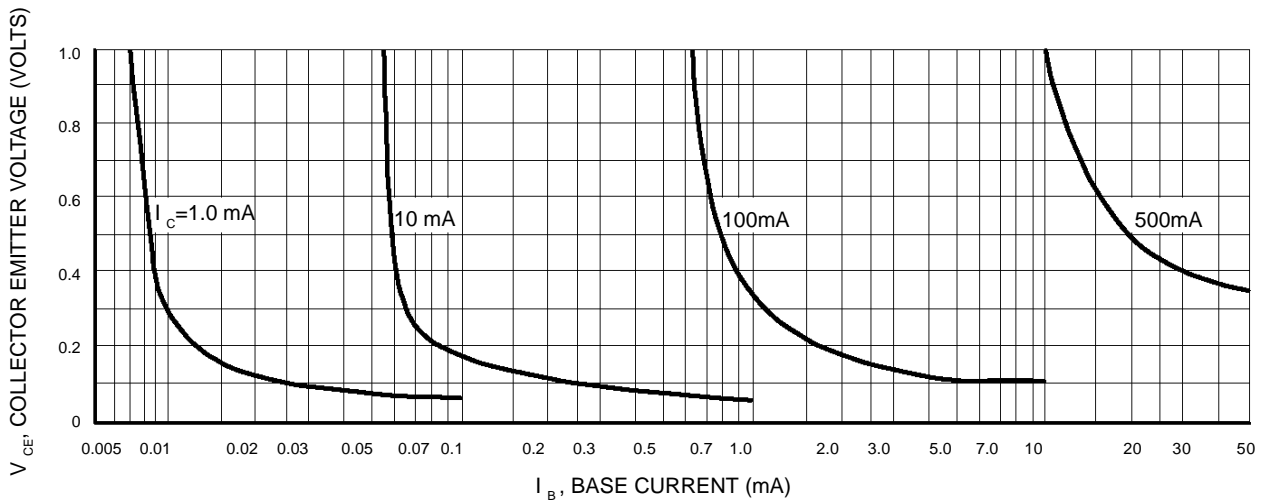


Figure 15. Collector Saturation Region

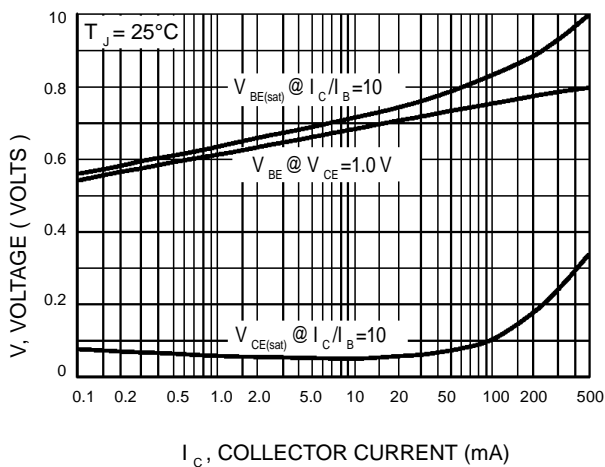


Figure 16. "On" Voltages

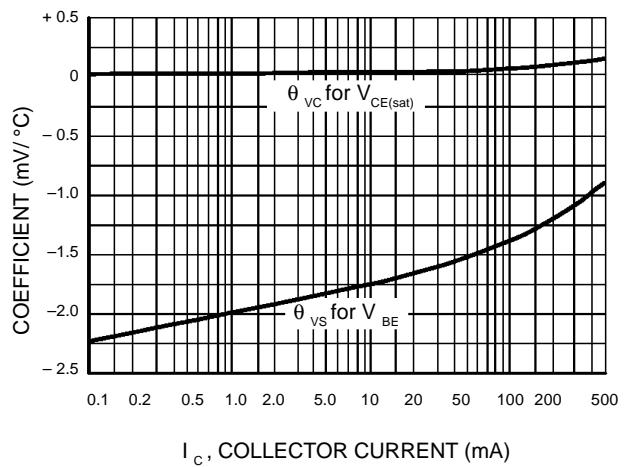
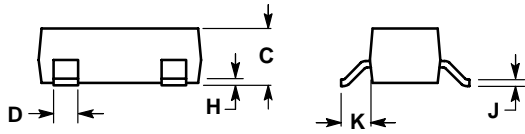
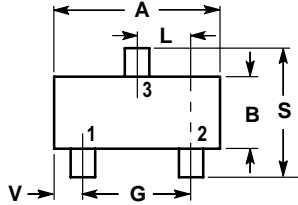


Figure 17. Temperature Coefficients

# PACKAGE OUTLINE & DIMENSIONS

## MMBT4403

### SOT-23



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

